MSKSEMI 美森科













FSD

15

TSS

MOV

GDT

PIFD

1N4148W-MS

Product specification





Features

- Fast switching speed
- Ultra-small surface mount package
- For general purpose switching applications
- High conductance

Reference News

PACKAGE OUTLINE	P-Channel MOSFET	Marking
2		T4
SOD-123		

Absolute Maximum Ratings (Ta = 25 °C)

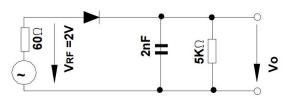
Parameter	Symbol	Value	Unit
Peak Reverse Voltage	V_{RM}	100	V
Reverse Voltage	V _R	75	V
Average Rectified Forward Current	I _{F(AV)}	150	Α
Non-repetitive Peak Forward Surge Current at t = 1 μs	I _{FSM}	2	Α
Power Dissipation	P _{tot}	400	W
Thermal Resistance from Junction to Ambient Air	R _{θJA}	312	°C/W
Junction Temperature	Tj	150	°C
Storage Temperature Range	T _{stg}	- 65 to + 150	°C



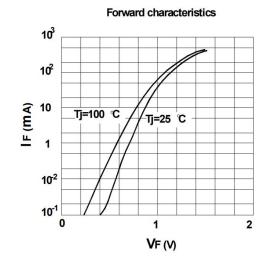
Characteristics at Ta = 25 ℃

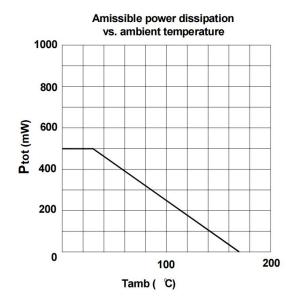
Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage		75		V
at I _R = 1 μA	$V_{(BR)R}$	75	-	V
Forward Voltage				
at I _F = 1 mA		_	0.715	
at I _F =10mA	V _F	_	0.855	V
at I _F =50 mA		_	1	
at I _F =150 mA		-	1.25	
Peak Reverse Current				
at V _R = 75 V		_	1	μA
at V _R = 20 V	I _R	_	25	nA
at V _R =75 V, T _J = 150 °C		_	50	μA
at V _R =25 V, T _J = 150 °C		-	30	μA
Total Capacitance	C-		2	nE
at $V_R = 0 V$, $f = 1 MHz$	Ст	-	2	pF
Reverse Recovery Time			4	ns
at I_{rr} = 0. 1 X I_R , I_F = I_R = 10 mA, R_L = 100 Ω	t _{rr}	-	4	113

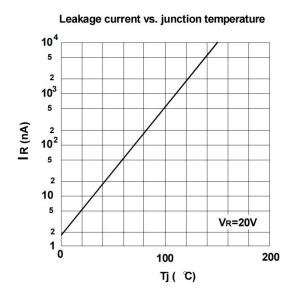


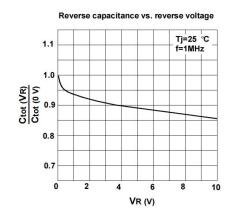


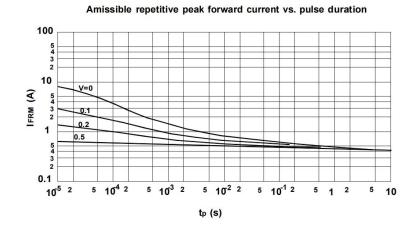
Rectification Efficiency Measurement Circuit





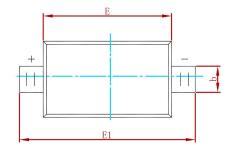


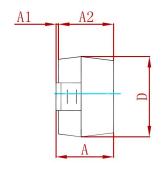


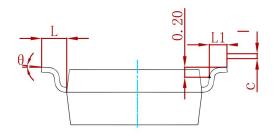




PACKAGE MECHANICAL DATA

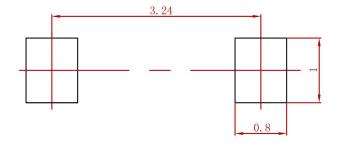






Symbol	Dimensions	In Millimeters	Dimensions	In Inches
	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
С	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500	REF	0.020	REF
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
1N4148W-MS	SOD-123	3000



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